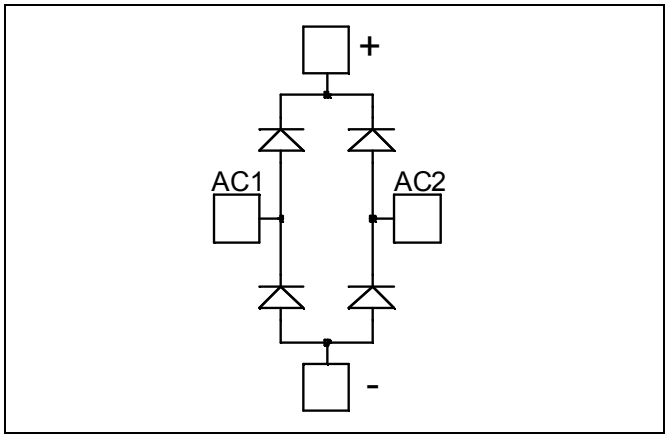
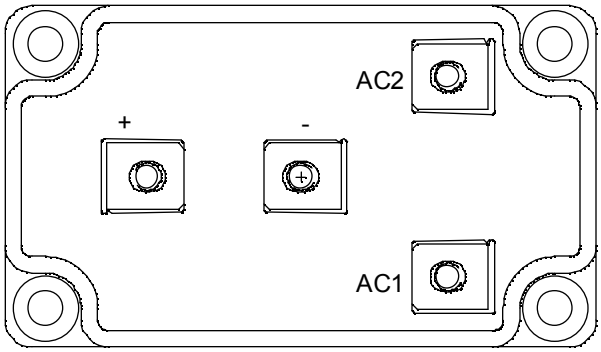
Diode Full Bridge Power Module

V_{RRM} = 1700V
I_C = 200A @ Tc = 55°C





Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

Absolute maximum ratings

Symbol	*Parameter*			*Max ratings*	*Unit*
V_R	Maximum DC reverse Voltage			1700	V
V_{RRM}	Maximum Peak Repetitive Reverse Voltage				
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50%	T_c = 25°C	240	A
			T_c = 55°C	200	
$I_{F(RMS)}$	RMS Forward Current			250	
I_{FSM}	Non-Repetitive Forward Surge Current		T_j = 25°C	600	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ T_j = 25°C unless otherwise specified

Electrical Characteristics

Symbol	*Characteristic*	*Test Conditions*		*Min*	*Typ*	*Max*	*Unit*
V_F	Diode Forward Voltage	I_F = 200A	T_j = 25°C		2.2	2.5	V
			T_j = 125°C		2.1		
I_{RM}	Maximum Reverse Leakage Current	V_R = 1700V	T_j = 25°C			350	µA
			T_j = 125°C			600	

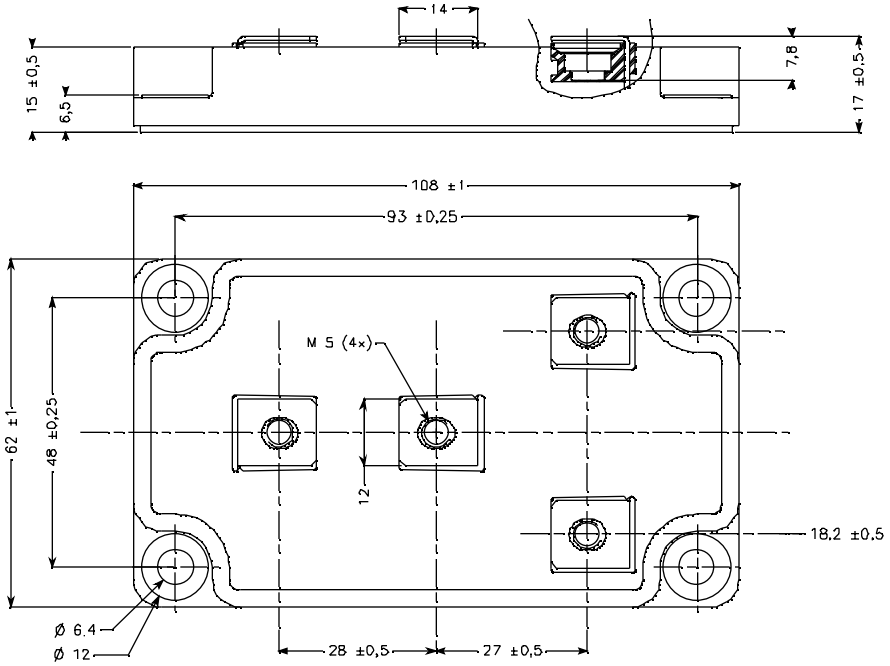
Dynamic Characteristics

Symbol	*Characteristic*	*Test Conditions*		*Min*	*Typ*	*Max*	*Unit*
t_{rr}	Reverse Recovery Time	I_F = 200A V_R = 900V di/dt = 2000A/µs	T_j = 25°C		572		ns
			T_j = 125°C		704		
Q_{rr}	Reverse Recovery Charge		T_j = 25°C		40		µC
			T_j = 125°C		70		
I_{RRM}	Reverse Recovery Current		T_j = 25°C		140		A
			T_j = 125°C		200		

Thermal and package characteristics

Symbol	*Characteristic*			*Min*	*Typ*	*Max*	*Unit*
R_{thJC}	Junction to Case Thermal Resistance					0.18	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, I isol<1mA, 50/60Hz			3500			V
T_J	Operating junction temperature range			-40		150	°C
T_{STG}	Storage Temperature Range			-40		125	
T_C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					280	g

SP6 Package outline (dimensions in mm)



Typical Performance Curve